AME5130

## ■ General Description

The AME5130 is a fixed off-time step-up DC/DC converter in a small 5-lead SOT-25 package.The AME5130 is ideal for LCD panels requiring low current and high efficiency as well as LED applications for cellular phone backlighting, PDAS, and other hand-held devices. The low 400 ns off-time allows the use of tiny external components.

AME5130 can drive up 8 white LEDs from a single LiIon battery DC 2 V to 5.5 V ; can be turned on by putting more than 1 V at pin $4(\mathrm{RUN})$. To control LED brightness, the LED current can be pulsed by applying a PWM (pulse width modulated) signal with a frequency range of 100 Hz to 50 KHz to the RUN pin.

Features

- $0.7 \Omega$ internal switch
- Uses small surface mount components
- Adjustable output voltage up to 20 V
- 2 V to 5.5 V input range
- Input undervoltage lockout
- $0.01 \mu \mathrm{~A}$ shutdown current
- Small 5-Lead SOT-25 package


## Applications

- White LED Back-Lighting
- Hand-held Devices
- Digital Cameras
- Portable Applications
- LCD Bias Power


## ■ Typical Application


${ }^{*} I_{\text {LED }}=V_{F B} / R 2$
Figure 1: Six White LEDs Application in Li-Ion Battery


Figure 2 : Typical 20V Application

Function Block Diagram


Figure 3 : AME5130 Block Diagram

■ Pin Configuration

| SOT-25 <br> Top View <br> 5 |  |  |  |  |
| :--- | :--- | :--- | :---: | :---: |

Pin Description

| Pin \# | Pin Name | Pin Description |
| :---: | :---: | :--- |
| 1 | SW | $\begin{array}{l}\text { Power Switch input. } \\ \text { This is the drain of the internal NMOS power switch. Minimize the metal trace area } \\ \text { connected to this pin to minimize EMI. }\end{array}$ |
| 2 | GND | $\begin{array}{l}\text { Ground. } \\ \text { Tie directly to ground plane. }\end{array}$ |
| 3 | FB | $\begin{array}{l}\text { Output voltage feedback input. } \\ \text { Set the output voltage by selecting values for R1 and R2 using: } \\ R 1=R 2\left(\frac{V_{\text {out }}}{1.23 V}-1\right) \\ \text { Connect the ground of the feedback network to an AGND(Analog Ground) plane which }\end{array}$ |
| should be tied directly to the GND pin. |  |  |\(\left.| \begin{array}{l}RUN <br>

\hline 4 <br>
\hline The shutdown pon is an active low. control. Tie this pin above 1V to enable the device. <br>
Tie this pin below 0.4V to turn off the device.\end{array}\right\}\)

## ■ Ordering Information



| Pin <br> Configuration | Operating <br> Temperature Range | Package Type | Number <br> of <br> Pins | Output Voltage | Special Feature |
| :--- | :--- | :--- | :--- | :--- | :--- |
| A 1. SW | E: $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ | E: SOT-2X | V: 5 | ADJ: Adjustable | Z: Lead free |
| 2. GND <br> 3. FB <br> 4. RUN <br> 5. VIN |  |  |  |  |  |

## ■ Ordering Information

| Part Number | Marking $^{*}$ | Output Voltage | Package | Operating Temp. Range |
| :---: | :---: | :---: | :---: | :---: |
| AME5130AEEVADJ | BCLww | ADJ | SOT- 25 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| AME5130AEEVADJZ | BCLww | ADJ | SOT- 25 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

Note: ww represents the date code and pls refer to Date Code Rule before Package Dimension.

* A line on top of the first letter represents lead free plating such as $\bar{B} C L$.

Please consult AME sales office or authorized Rep./Distributor for the availability of package type.

■ Absolute Maximum Ratings

| Parameter | Symbol | Maximum | Unit |
| :--- | :---: | :---: | :---: |
| Input Supply Voltage | $\mathrm{V}_{\mathrm{IN}}$ | 6 | V |
| RUN, $\mathrm{V}_{\mathrm{FB}}$ Voltages | $\mathrm{V}_{\mathrm{RUN}}, \mathrm{V}_{\mathrm{FB}}$ | $\mathrm{V}_{\mathrm{IN}}$ | V |
| SW Voltage | $\mathrm{V}_{\mathrm{SW}}$ | $\mathrm{V}_{\text {OUT }+0.3}$ | V |
| N-Channel Switch Sink Current | $\mathrm{I}_{\mathrm{SW}}$ | 800 | mA |
| ESD Classification |  | B |  |

Caution: Stress above the listed absolute maximum rating may cause permanent damage to the device

Recommended Operating Conditions

| Parameter | Rating | Unit |
| :--- | :---: | :---: |
| Ambient Temperature Range | -40 to +85 | ${ }^{\circ} \mathrm{C}$ |
| Junction Temperature | -40 to +125 | ${ }^{\circ} \mathrm{C}$ |

## ■ Thermal Information

| Parameter | Package | Die Attached | Symbol | Maximum | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Thermal Resistance* (Junction to Case) | SOT-25 | Conductive | $\theta_{\text {Jc }}$ | 81 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal Resistance (Junction to Ambient) |  |  | $\theta_{\text {JA }}$ | 260 |  |
| Internal Power Dissipation $\left(\Delta \mathrm{T}=100^{\circ} \mathrm{C}\right)$ |  |  | PD | 400 | mW |
| Maximum Junction Temperature |  |  |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| Lead Temperature (Soldering 10sec) |  |  |  | 300 | ${ }^{\circ} \mathrm{C}$ |

* The case point of $\theta_{\mathrm{Jc}}$ is on the center of Molding Compound.


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Electrical Specifications
$\mathrm{V}_{\mathrm{IN}}=2.2 \mathrm{~V}, \mathrm{RUN}=\mathrm{V}_{\mathrm{iN},} \mathrm{TA}=25^{\circ} \mathrm{C}$ Unless otherwise noted.

| Parameter | Symbol | Test Condition | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Device Disabled | $\mathrm{l}_{\mathrm{Q}}$ | $\mathrm{FB}=1.3 \mathrm{~V}$ |  | 64 | 80 | $\mu \mathrm{A}$ |
| Device Enabled |  | $\mathrm{FB}=1.15 \mathrm{~V}$ |  | 69 | 90 |  |
| Shutdown |  | $R U N=0 V$ |  | 0.01 | 2 |  |
| Feedback Trip Point | $V_{\text {FB }}$ |  | 1.199 | 1.23 | 1.261 | V |
| Switch Current Limit | $\mathrm{I}_{\mathrm{CL}}$ | $\mathrm{l}_{\text {OUT }}=20 \mathrm{~mA}, \mathrm{~V}_{\text {OUT }}=20 \mathrm{~V}$ | 490 | 550 | 610 | mA |
| FB Pin Bias Current | $\mathrm{I}_{\mathrm{B}}$ | $\mathrm{FB}=1.23 \mathrm{~V}$ |  | 0.2 | 0.7 | $\mu \mathrm{A}$ |
| Input Voltage Range | $\mathrm{V}_{\text {IN }}$ |  | 2 |  | 5.5 | V |
| Switch R ${ }_{\text {DSoN }}$ | $\mathrm{R}_{\text {DSON }}$ |  |  | 0.7 | 1.6 | $\Omega$ |
| Switch Off Time | T OFF |  |  | 400 |  | ns |
| RUN Pin Current | $I_{\text {SD }}$ | RUN $=\mathrm{V}_{\text {IN }}, \mathrm{T}_{J}=25^{\circ} \mathrm{C}$ |  | 0 |  | nA |
|  |  | $R U N=V_{\text {IN }}, T_{J}=125^{\circ} \mathrm{C}$ |  | 15 |  | nA |
|  |  | RUN = GND |  | 0 |  | nA |
| Switch Leakage Current | IL | $\mathrm{V}_{\mathrm{SW}}=20 \mathrm{~V}$ |  | 0.05 | 5.0 | $\mu \mathrm{A}$ |
| Input Undervoltage Lockout | UVP | ON/OFF Threshold |  | 1.6 |  | V |
| Feedback Hysteresis | $V_{F B}$ <br> Hysteresis |  |  | 8 |  | mV |
| RUN Low (Shutdown) | RUN Threshold |  |  |  | 0.4 | V |
| RUN High <br> (Enable the device) |  |  | 1 |  |  | V |

## ■ Electrical Specifications

The AME5130 features a constant off-time control scheme. Operation can be best understood by referring to Figure 3. When the voltage at the FB pin is less than 0.9 V , the Enable Comp in Figure 3 enables the device and the NMOS switch is turmed on pulling the SW pin to ground. When the NMOS switch is on, current is supplied by the output capacitor $\mathrm{C}_{\text {out. }}$. Once the current in the inductor reaches the peak current limit, the 400ns One Shot turns off the NMOS switch. The SW voltage will then rise to the output voltage plus a diode drop and the inductor current will begin to decrease as shown in Figure 3. During this time the energy stored in the inductor is transferred to $\mathrm{C}_{\text {out }}$ and the load. After the 400 ns off-time the NMOS switch is turned on and energy is stored in the inductor again. This energy transfer from the inductor to the output causes a stepping effect in the output ripple.

This cycle is continued until the voltage at FB reaches 1.23 V . When FB reaches this voltage, the enable comparator then disables the device turning off the NMOS switch and reducing the lq of the device to $64 \mu \mathrm{~A}$. The load current is then supplied solely by C out indicated by the gradually decreasing slope at the output. When the FB pin drops slightly below 1.23 V , the enable comparator enables the device and begins the cycle described previously. The RUN pin can be used to turn off the AME5130 and reduce the Iq to $0.01 \mu \mathrm{~A}$. In shutdown mode the output voltage will be a diode drop lower than the input voltage.

## Application Information

## INDUCTOR SELECTION

The appropriate inductor for a given application is calculated using the following equation:


Where $\mathrm{V}_{\mathrm{D}}$ is the schottky diode voltage, $\mathrm{I}_{\mathrm{CL}}$ is the switch current limit found in the Typical Performance Characteristics section, and $T_{\text {OFF }}$ is the switch off time. When using this equation be sure to use in minimum input voltage for the application, such as for battery powered applications.

Choosing inductors with low ESR decrease power lossed and increase efficiency.

Care should be taken when choosing an inductor. For applications that require an input voltage that approaches the output voltage, such as when converting a Li-ion battery voltage to 5 V , the 400 ns off time may not be enough time to discharge the energy in the inductor and transfer the energy to the output capacitor and load. This can cause a ramping effect in the inductor current waveform and an increased ripple on the output voltage. Using a smaller inductor will cause the I ${ }_{\text {PK }}$ to increase and will increase the output voltage ripple further. This can be solved by adding a 4.7 pF capacitor across the R1 feedback resistor (Figure 3) and slightly increasing the output capacitor. A smaller inductor can then be used to ensure proper discharge in the 400ns off time.

## DIODE SELECTION

To maintain high efficiency, the average current rating of the schottky diode should be larger than the peak inductor current, I ${ }_{\text {PK }}$. Schottky diodes with a low forward drop and fast switching speeds are ideal for increasing efficiency in portable applications. Choose a reverse breakdown of the schottky diode larger than the output voltage.

## CAPACITOR SELECTION

Choose low ESR capacitors for the output to minimize output voltage ripple. Multilayer ceramic capacitors are the best choice. For most applications, a $1 \mu \mathrm{~F}$ ceramic capacitor is sufficient. For some applications a reduction in output voltage ripple can be achieved by increasing the output capacitor. Local bypassing for the input is needed on the AME5130. Multilayer ceramic capacitors are a good choice for this as well. A $4.7 \mu \mathrm{~F}$ capacitor is sufficient for most applications. For additional bypassing, a 100 nF ceramic capacitor can be used to shunt high frequency ripple on the input.

## LAYOUT CONSIDERATIONS

The input bypass capacitor $\mathrm{C}_{{ }_{\mathrm{N}}}$, as shown in Figure 3, must be placed close to the IC. This will reduce copper trace resistance which effects input voltage ripple of the IC. For additional input voltage filtering, a 100 nF bypass capacitor can be placed in parallel with $\mathrm{C}_{\text {IN }}$ to shunt any high frequency noise to ground. The output capacitor, C out should also be placed close to the IC. Any copper trace connections for the C оит capacitor can increase the series resistance, which directly effects output voltage ripple. The feedback network, resistors R1 and R2, should be kept close to the FB pin to minimize copper trace connections that can inject noise into the system. The ground connection for the feedback resistor network should connect directly to an analog ground plane. The analog ground plane should tie directly to the GND pin. If no analog ground plane is available, the ground connection for the feedback network should tie directly to the GND pin. Trace connections made to the inductor and schottky diode should be minimized to reduce power dissipation and increase overall efficiency.

Application Information


Figure4: Eight White LEDs Application in Li-Ion Battery


Figure5: Li-Ion 5V Application

AME5130

Application Information


Figure6: Li-Ion 12V Application


Figure7: 5V to 12V Application

AME5130
Micropower Step-Up DC/DC Converter

Switch Current Limit vs. $\mathrm{V}_{\mathrm{IN}}$


Efficiency vs. Load Current


Enable Current vs. $\mathrm{V}_{\mathrm{IN}}$ (Part Switching)


Efficiency vs. Load Current


Efficiency vs. Load Current


Disable Current vs. $\mathrm{V}_{\mathrm{IN}}$ (Part Not Switching)



Efficiency vs. $\mathrm{V}_{\mathrm{IN}}$


FB Trip Point and FB Pin Current vs Temperature


Switch Rdson vs. $\mathrm{V}_{\mathrm{IN}}$


Efficiency vs. $\mathrm{V}_{\mathbb{I N}}$


Output Voltage vs Load Current


Typical Switching Waveform

$\mathrm{V}_{\text {OUT }}=19.4 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=4.2 \mathrm{~V} ; 6$ LEDs
$\mathrm{l}_{\text {OUT }}=15 \mathrm{~mA}$

1) $V_{s w}, 20 \mathrm{~V} /$ div, $D C$
2) Inductor current, $500 \mathrm{~mA} / \mathrm{div}, \mathrm{DC}$
3) $\mathrm{V}_{\text {OUT }}, 100 \mathrm{mV} / \mathrm{div}, \mathrm{AC}$

Start-Up/Shutdown

$V_{\text {out }}=20 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=2.5 \mathrm{~V}$

1) Vout, $100 \mathrm{mV} /$ div.AC
2) $V s w, 20 \mathrm{~V} / \mathrm{div}, \mathrm{DC}$
3) Inductor Current $500 \mathrm{~mA} /$ div, DC
$\mathrm{T}=20 \mu \mathrm{~s} / \mathrm{div}$

Typical Switching Waveform

$\mathrm{V}_{\text {OUT }}=13.25 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=4.2 \mathrm{~V}$; 8 LEDs
$\mathrm{l}_{\text {OUT }}=30 \mathrm{~mA}$

1) $V_{S W}, 20 \mathrm{~V} / \mathrm{div}, D C$
2) Inductor current, $500 \mathrm{~mA} / \mathrm{div}, \mathrm{DC}$
3) $\mathrm{V}_{\text {out }}, 100 \mathrm{mV} / \mathrm{div}, \mathrm{AC}$

Start-Up/Shutdown

$\mathrm{V}_{\text {OUT }}=20 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=2.5 \mathrm{~V}$

1) RUN, $1 \mathrm{~V} / \mathrm{div}, D C$
2) $\mathrm{V}_{\text {OUT }}, 20 \mathrm{~V} / \mathrm{div}, \mathrm{DC}$
3) $\mathrm{I}_{\mathrm{L}}, 200 \mathrm{~mA} / \mathrm{div}, \mathrm{DC}$
$\mathrm{T}=400 \mu \mathrm{~s} / \mathrm{div}$
$R_{L}=1.3 \mathrm{k} \Omega$

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■ Date Code Rule

| Marking |  |  | Date Code |  | Year |
| :---: | :---: | :---: | :---: | :---: | :---: |
| A | A | A | W | W | xxx0 |
| A | A | A | W | W | xxx1 |
| A | A | A | W | W | xxx2 |
| A | A | A | W | W | xxx3 |
| A | A | A | W | W | xxx4 |
| A | A | A | W | W | xxx5 |
| A | A | A | W | W | xxx6 |
| A | A | A | W | W | xxx7 |
| A | A | A | W | W | xxx8 |
| A | A | A | W | W | xxx9 |

## Tape and Reel Dimension

## SOT-25



Carrier Tape, Number of Components Per Reel and Reel Size

| Package | Carrier Width (W) | Pitch (P) | Part Per Full Reel | Reel Size |
| :---: | :---: | :---: | :---: | :---: |
| SOT-25 | $8.0 \pm 0.1 \mathrm{~mm}$ | $4.0 \pm 0.1 \mathrm{~mm}$ | 3000 pcs | $180 \pm 1 \mathrm{~mm}$ |

## AME, Inc.

AME5130
Micropower Step-Up DC/DC Converter
■ Package Dimension

SOT-25


| SYMBOLS | MILLIMETERS |  | INCHES |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |
| A | 1.20REF |  | 0.0472REF |  |
| $\mathrm{A}_{1}$ | 0.00 | 0.15 | 0.0000 | 0.0059 |
| b | 0.30 | 0.55 | 0.0118 | 0.0217 |
| D | 2.70 | 3.10 | 0.1063 | 0.1220 |
| E | 1.40 | 1.80 | 0.0551 | 0.0709 |
| e | 1.90 BSC |  | 0.07480 BSC |  |
| H | 2.60 | 3.00 | 0.10236 | 0.11811 |
| L | 0.37BSC |  | 0.0146BSC |  |
| $\theta 1$ | $0^{\circ}$ | $10^{\circ}$ | $0^{\circ}$ | $10^{\circ}$ |
| $\mathrm{S}_{1}$ | 0.95BSC |  | $0.0374 B S C$ |  |

## Life Support Policy:

These products of AME, Inc. are not authorized for use as critical components in life-support devices or systems, without the express written approval of the president
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AME, Inc. reserves the right to make changes in the circuitry and specifications of its devices and advises its customers to obtain the latest version of relevant information.
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